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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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TECHNICAL DATA SHEET

6 Lake Street, Lawrence, MA 01841 1-800-446-1158 / (978) 620-2600 / Fax: (978) 689-0803

Website: http://www.microsemi.com

NPN POWER SILICON TRANSISTOR

Qualified per MIL-PRF-19500/464

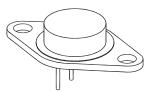
DEVICES

2N5685 2N5686

JAN
JANTX
JANTV

ABSOLUTE MAXIMUM RATINGS ($T_C = +25^{\circ}C$ unless otherwise noted)

Parameters / Test Conditions	Symbol	2N5685	2N5686	Unit
Collector-Emitter Voltage	V_{CEO}	60	80	Vdc
Collector-Base Voltage	V_{CBO}	60	80	Vdc
Emitter-Base Voltage	V_{EBO}	5.0	5.0	Vdc
Base Current	I_{B}	15	15	Adc
Collector Current	I_{C}	50	50	Adc
Total Power Dissipation $\textcircled{0}$ $T_C = +25^{\circ}C^{(1)}$ $\textcircled{0}$ $T_C = +100^{\circ}C^{(1)}$	P _T	300 171	300 171	W W
Operating & Storage Junction Temperature Range	T_J, T_{stg}	-55 to +200		°C



TO-3 (TO-204AE)

THERMAL CHARACTERISTICS

Parameters / Test Conditions	Symbol	Max.	Unit
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$.0584	°C/W

Note:

1. Derate linearly 1.715 W/°C between $T_C = 25$ °C and $T_C = 200$ °C

ELECTRICAL CHARACTERISTICS ($T_A = +25^{\circ}C$, unless otherwise noted)

Parameters / Test Conditions	Symbol	Min.	Max.	Unit	
OFF CHARACTERTICS (1)					
Collector-Emitter Breakdown Voltage					
$I_C = 100 \text{mAdc}$	2N5685	$V_{(BR)CEO}$	60		Vdc
	2N5686		80		
Collector-Emitter Cutoff Current					
$V_{CE} = 30 Vdc$	2N5685	I_{CEO}		500	μAdc
$V_{CE} = 40 \text{Vdc}$	2N5686			500	
Collector-Emitter Cutoff Current					
$V_{CE} = 60 \text{Vdc}, V_{BE} = 1.5 \text{Vdc}$	2N5685	I_{CEX}		10	A 1
$V_{CE} = 80 \text{Vdc}, V_{BE} = 1.5 \text{Vdc}$	2N5686			10	μAdc
Collector-Base Cutoff Current					
$V_{CE} = 60 \text{Vdc}$	2N5685	I_{CBO}		2.0	A 1
$V_{CE} = 80 \text{Vdc}$	2N5686			2.0	mAdc
Emitter-Base Cutoff Current		Irno		1.0	mAdc
$V_{EB} = 5.0 \text{Vdc}$		$I_{ m EBO}$		1.0	made



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ELECTRICAL CHARACTERISTICS ($T_A = +25^{\circ}C$, unless otherwise noted)

Parameters / Test Conditions	Symbol	Min.	Max.	Unit	
ON CHARACTERISTICS (2)					
Forward-Current Transfer Ratio $I_C = 5.0 Adc, V_{CE} = 2.0 Vdc$ $I_C = 25 Adc, V_{CE} = 2.0 Vdc$ $I_C = 50 Adc, V_{CE} = 5.0 Vdc$	$h_{ m FE}$	30 15 5.0	60		
Collector-Emitter Saturation Voltage $I_C = 25 Adc, I_B = 2.5 Adc$ $I_C = 50 Adc, I_B = 10 Adc$	V _{CE(sat)}		1.0 5.0	Vdc	
Base-Emitter Saturation Voltage $I_C = 25$ Adc, $I_B = 2.5$ Adc	V _{BE(sat)}		2.0	Vdc	
Base-Emitter Voltage $I_C = 25 Adc$, $V_{CE} = 2.0 Adc$	V _{BE(ON)}		2.0	Vdc	

DYNAMIC CHARACTERISTICS

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
Magnitude of Common Emitter Small-Signal Short-Circuit, Forward Current Transfer Ratio $I_C = 5.0 Adc, V_{CE} = 10 Vdc, f = 1.0 MHz$	$ \mathbf{h}_{\mathrm{fe}} $	2.0	20	
Small-Signal Short-Circuit Forward Current Transfer Ratio $I_C = 10 Adc, V_{CE} = 5.0 Vdc, f = 1.0 kHz$	h_{fe}	15		
Output Capacitance $V_{CB} = 10 V dc$, $I_E = 0$, $0.1 MHz \le f \le 1.0 MHz$	C _{obo}		1200	pF

SWITCHING CHARACTERISTICS

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
Turn-On Time $V_{CC} = 30 \text{Vdc}$; $I_C = 25 \text{Adc}$; $I_{B1} = 2.5 \text{Adc}$	t _{on}		1.5	μs
Turn-Off Time $V_{CC} = 30Vdc$; $I_C = 25Adc$; $I_{B1} = -I_{B2} = 2.5Adc$	$t_{ m off}$		3.0	μs

SAFE OPERATING AREA

DC Tests

 $T_C = +25$ °C, 1 Cycle, t = 1.0s

Test 1

 $V_{CE} = 6.0 \text{Vdc}, I_C = 50 \text{Adc}$

Test 2

 $V_{CE} = 30 \text{Vdc}, I_C = 10 \text{Adc}$

Test 3

 $V_{CE} = 50 \text{Vdc}, I_{C} = 560 \text{mAdc}$ 2N5685 $V_{CE} = 60 \text{Vdc}, I_{C} = 640 \text{mAdc}$ 2N5686

(2) Pulse Test: Pulse Width = $300\mu s$, Duty Cycle $\leq 2.0\%$



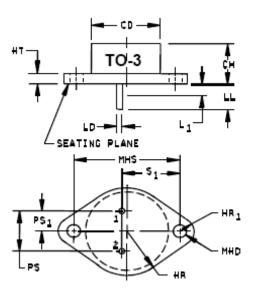
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PACKAGE DIMENSIONS



Dimensions					
Ltr	Inc	Inches		Millimeters	
	Min	Max	Min	Max	
CD		.875		22.22	3
СН	.250	.450	6.35	11.43	
HR	.495	.525	12.57	13.34	
HR_1	.131	.188	3.33	4.78	6
HT	.060	.135	1.52	3.43	
LD	.057	.063	1.45	1.60	4, 5, 9
LL	.312	.500	7.92	12.70	4, 5, 9
L_1		.050		1.27	5, 9
MHD	.151	.165	3.84	4.19	7
MHS	1.177	1.197	29.90	30.40	
PS	.420	.440	10.67	11.18	
PS_1	.205	.225	5.21	5.72	5
S_1	.655	.675	16.64	17.15	

NOTE:

- 1. Dimensions are in inches.
- 2. Millimeters are given for general information only.
- 3. Body contour is optional within zone defined by CD.
- 4. These dimensions shall be measured at points .050 inch (1.27 mm) to .055 inch (1.40 mm) below seating plane. When gauge is not used, measurement shall be made at seating plane.
- 5. Both terminals.
- 6. At both ends.
- 7. Two holes.
- 8. The collector shall be electrically connected to the case.
- 9. LD applies between L₁ and LL. Lead diameter shall not exceed twice LD within L₁.
- 10. In accordance with ASME Y14.5M, diameters are equivalent to φx symbology.
- * 11. Terminal 1 is emitter; terminal 2 is base; case is collector.

* FIGURE 1. Physical dimensions (TO-3)

T4-LDS-0162 Rev. 1 (100546)